

### 40V N-Channel Enhancement Mode MOSFET

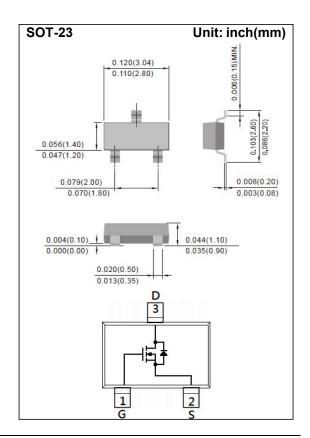
Voltage 40 V Current 4A

### **Features**

- RDS(ON), VGS@10V, ID@4.4A<48mΩ
- RDS(ON), VGS@4.5V, ID@2.8A<70m $\Omega$
- Advanced Trench Process Technology
- Specially Designed for switch Load, PWM applications, and solid-state relays relay

### **Mechanical Data**

- Case: SOT-23 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0003 ounces, 0.0084 grams



# **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V <sub>DS</sub>	40	V
Gate-Source Voltage		V <sub>GS</sub>	<u>+</u> 20	V
Continuous Drain Current		I <sub>D</sub>	4	Α
Pulsed Drain Current		I <sub>DM</sub>	16	Α
Power Dissipation	T <sub>a</sub> =25°C		1.25	W
	Derate above 25°C	P <sub>D</sub>	10	mW/°C
Operating Junction and Storage Tem	$T_{J}, T_{STG}$	-55~150	°C	
Typical Thermal resistance				
Junction to Ambient (Note 3)		R <sub>0JA</sub>	100	°C/W



# **Electrical Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250uA	40	-	-	V	
Gate Threshold Voltage	$V_{GS(th)}$	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250uA	1.0	1.37	2.1	V	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =4.4A	-	35	48	mΩ	
		V <sub>GS</sub> =4.5V, I <sub>D</sub> =2.8A	-	51	70		
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =40V, V <sub>GS</sub> =0V	-	0.01	1	uA	
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 20V, V <sub>DS</sub> =0V	-	<u>+</u> 10	<u>+</u> 100	nA	
Dynamic							
Total Gate Charge	$Q_g$	V <sub>DS</sub> =15V, I <sub>D</sub> =4.4A, V <sub>GS</sub> =10V <sup>(Note 1,2)</sup>	-	5.8	-	nC	
Gate-Source Charge	$Q_{gs}$		-	1	-		
Gate-Drain Charge	$Q_{gd}$		-	1	-		
Input Capacitance	Ciss	V <sub>DS</sub> =15V, V <sub>GS</sub> =0V, f=1.0MHZ	-	235	-	pF	
Output Capacitance	Coss		-	36	-		
Reverse Transfer Capacitance	Crss		-	24	-		
Switching							
Turn-On Delay Time	td <sub>(on)</sub>	$V_{DD}$ =15V, $I_{D}$ =4.4A, $V_{GS}$ =10V, $R_{G}$ =6 $\Omega$ (Note 1,2)	-	3	-		
Turn-On Rise Time	tr		-	39	-		
Turn-Off Delay Time	td <sub>(off)</sub>		-	23	-	ns	
Turn-Off Fall Time	tf		-	28	-		
Drain-Source Diode							
Maximum Continuous Drain-Source	Is		_	_	1.5	Α	
Diode Forward Current					1.0	, ,	
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =1.0A, V <sub>GS</sub> =0V	-	0.77	1.2	V	

### NOTES:

- 1. Pulse width < 300us, Duty cycle < 2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
- 4. The maximum current rating is package limited



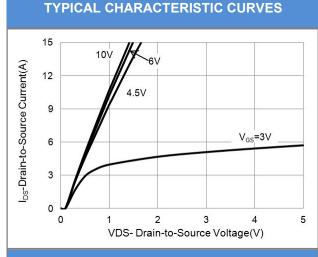
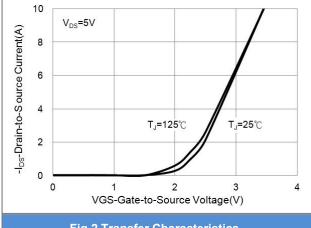


Fig.1 On-Region Characteristics



**Fig.2 Transfer Characteristics** 

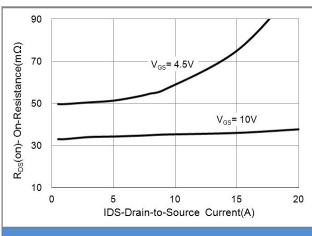


Fig.3 On-Resistance vs. Drain Current

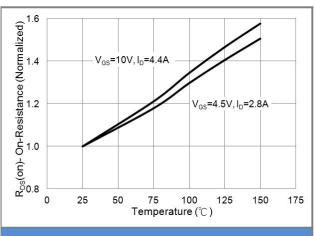


Fig.4 On-Resistance vs. Junction temperature

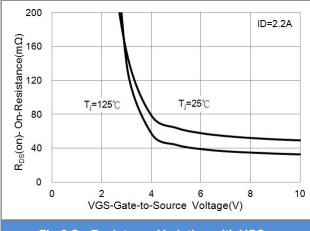
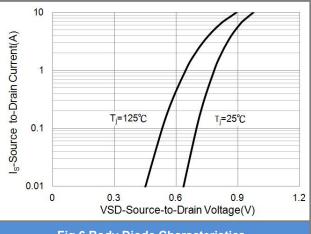


Fig.5 On-Resistance Variation with VGS.



**Fig.6 Body Diode Characteristics** 



2

0

0

# CSM2318S23

# **TYPICAL CHARACTERISTIC CURVES** 10 V<sub>DS</sub>= 15V ID=4.4A Gate-Source Voltage-V<sub>GS</sub>(Volts) 8 6 4

Fig.7 Gate-Charge Characteristics

3

Qg(nC)

4

5

6

2

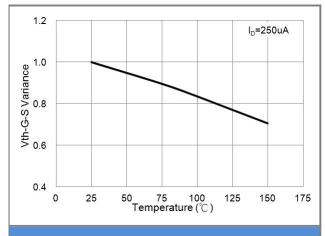
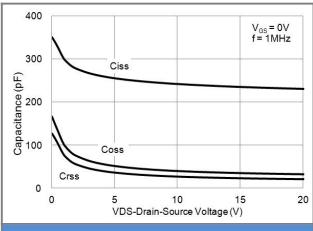


Fig.8 Threshold Voltage Variation with Temperature.

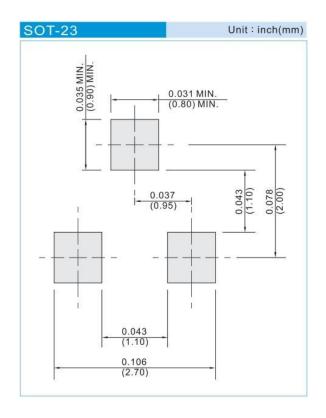




## PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type		
CSM2318S23	SOT-23	3K pcs / 7" reel		

## **MOUNTING PAD LAYOUT**





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